TOSHIBA Transistor Silicon Epitaxial Planar Type

2SC4203

Video Output for High Definition VDT High Speed Switching Applications

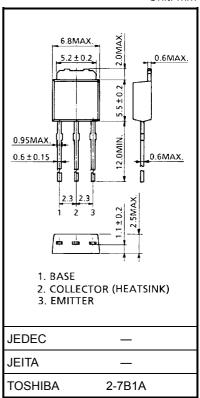
• High transition frequency: $f_T = 400 \text{ MHz}$ (typ.)

(V_{CE} = 10 V, I_C = 70 mA)

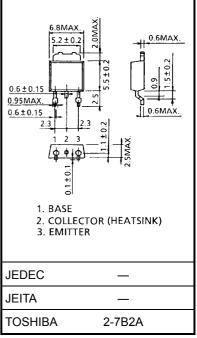
- Low output capacitance: $C_{ob} < 5 \text{ pF} (max) (V_{CB} = 30 \text{ V})$
- High voltage: V_{CEO} = 150 V
- High power dissipation: $P_C = 10 W$

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	180	V	
Collector-emitter voltage		V _{CEO}	150	V	
Emitter-base voltage		V _{EBO}	5	V	
Collector current (DC)		Ι _C	0.3	A	
Collector current (pulse)		I _{CP}	0.5	А	
Base current		Ι _Β	0.2	А	
Power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	ГC	10		
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.36 g (typ.)

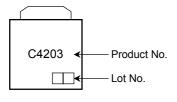


Weight: 0.36 g (typ.)

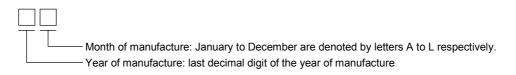
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 150 V, I _E = 0	_	_	10	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0		—	10	μA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 1 mA, I _B = 0	150	—	—	V
DC current gain	h _{FE (1)}	V _{CE} = 10 V, I _C = 50 mA	40	_	240	
	h _{FE (2)}	V _{CE} = 10 V, I _C = 200 mA	20	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 200 mA, I _B = 20 mA	_	_	2.0	V
Base-emitter saturation voltage	V _{BE (sat)}	I _C = 200 mA, I _B = 20 mA	_	_	1.5	V
Transition frequency	f _T	V _{CE} = 10 V, I _C = 70 mA	300	400	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 30 V, f = 1 MHz, I _E = 0	_	4.0	5.0	pF

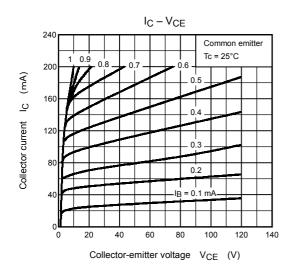
Marking

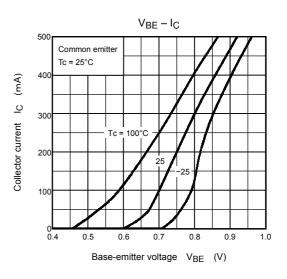


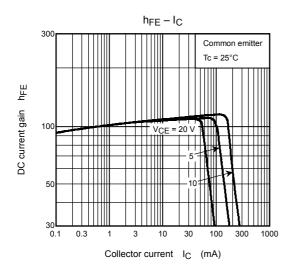
Explanation of Lot No.

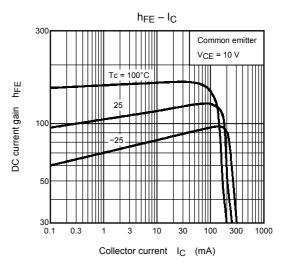


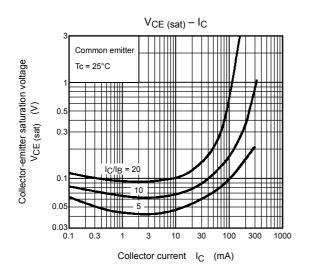
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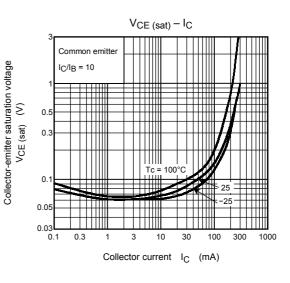




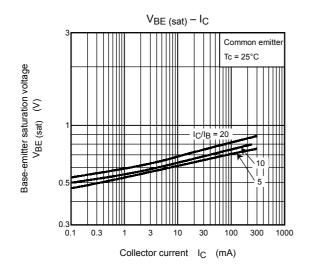


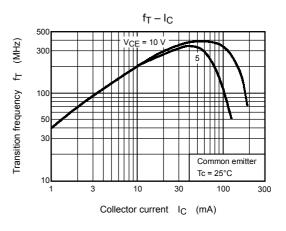


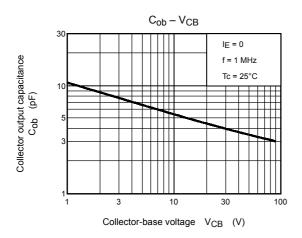


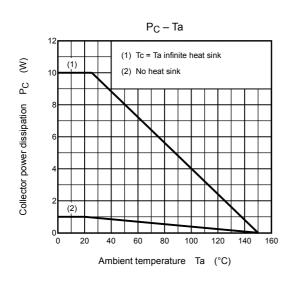


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